

BLT50,115

BLT50,115 Information

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For Reference Only

Part Number	BLT50,115	
Manufacturer	NXP	
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF	
Description	TRANS NPN 7.5V SOT223	
Package	TO-261-4, TO-261AA	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BLT50,115 Specifications

Manufacturer Part Number	BLT50,115
Manufacturer	NXP
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-261-4, TO-261AA
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	10V
Frequency - Transition	470MHz
Noise Figure (dB Typ @ f)	-
Gain	-
Power - Max	2W
DC Current Gain (hFE) (Min) @ Ic, Vce	25 @ 300mA, 5V
Current - Collector (Ic) (Max)	500mA
Operating Temperature	175°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-261-4, TO-261AA
Supplier Device Package	SOT-223
	Report errors?

BLT50,115 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BLT50,115 Payment Methods WIRE ransfer PayPal WIRE of PayPal MoneyGram Alie In Internet Inte

If you have any question about BLT50,115, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com